

Isc N-Channel MOSFET Transistor

IRF3315L

pin 1, Oate

3

2

2, Drain

3, Source

D(2)

FEATURES

- With To-262 package
- Low input capacitance and gate charge
- Low gate input resistance
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

Switching applications

• ABSOI	LUTE MAXIMUM RATINGS(Ta=25°C	1 TO-262 package			
SYMBOL	PARAMETER	VALUE	UNIT		
V _{DSS}	Drain-Source Voltage	150	V		
V _{GSS}	Gate-Source Voltage	±20	V		
I _D	Drain Current-ContinuousTc=25℃ Tc=100℃	21 15	А		
I _{DM}	Drain Current-Single Pulsed	84	А		
PD	Total Dissipation @Tc=25°C	94	W	mm DIM MIN MAX A 4.37 4.77 A1 1.22 1.42	
Tch	Max. Operating Junction Temperature	175	°C	A2 2.47 2.87 b 0.70 0.97 b2 1.17 1.42	
T _{stg}	Storage Temperature	-55~175	°C	c 0.28 0.53 D 23.20 24.02 D1 8.38 8.90 D2 6.00 -	
THERMAL CHARACTERISTICS				E 9.90 10.39 E4 7.30 e 2.54BSC	
SYMBOL	PARAMETER	МАХ	UNIT	$\begin{array}{c ccccc} G & 1.25 & 1.50 \\ \hline H2 & - & 1.31 \\ \hline L & 13.34 & 14.10 \\ \end{array}$	
Rth(ch-c)	Channel-to-case thermal resistance	1.6	°C/W	L1 3.30 4.06 L3 0.95 1.15	

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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D =0.25mA	150			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} =V _{GS} ; I _D =0.25mA	2.0		4.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =12A			82	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±30V;V _{DS} =0V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} =150V; V _{GS} = 0V;Tj=25℃ V _{DS} =120V; V _{GS} = 0V;Tj=150℃			25 250	μA
V _{SDF}	Diode forward voltage	I _{SD} =21A, V _{GS} = 0 V			1.3	V

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